

LMC606x Precision CMOS, Micropower Operational Amplifiers

1 Features

- Typical values unless otherwise noted
- Low offset voltage: 100µV
- Ultra-low supply current: 16µA/amplifier
- Supply range: 4.5V to 15V
- Ultra-low input bias current: 10fA
- Output swing within 10mV of supply rail, $100k\Omega$ • load
- Input common-mode includes V-
- High voltage gain: 140dB
- Improved latchup immunity

2 Applications

- Instrumentation amplifier
- Photodiode and infrared detector preamplifier
- Transducer amplifiers
- Portable analytic instruments
- Medical instrumentation
- Digital-to-analog converter (DAC)
- Charge amplifier for piezoelectric transducers

3 Description

The LMC6061, LMC6062, and LMC6064 (LMC606x) low-offset-voltage, precision, micropower are operational amplifiers (op amps), capable of precision single-supply operation. Performance characteristics include ultra-low input bias current, high voltage gain, rail-to-rail output swing, and an input common-mode voltage range that includes ground. These features, plus the low power consumption of the op amps, make the LMC606x an excellent choice for batterypowered applications.

Other applications using the LMC606x include precision full-wave rectifiers, integrators, references, sample-and-hold circuits, and true instrumentation amplifiers.

This device is built with TI's advanced double-poly silicon-gate CMOS process.

For designs that require higher speed, see the LMC608x precision operational amplifiers.

PATENT PENDING

Device Information						
PART NUMBER CHANNEL COUNT PACKAGE ⁽¹⁾						
LMC6061	Single	D (SOIC, 8)				
LMC6062	Dual	D (SOIC, 8)				
	Duai	P (PDIP, 8)				
LMC6064	Quad	D (SOIC, 8)				

For more information, see Section 9. (1)

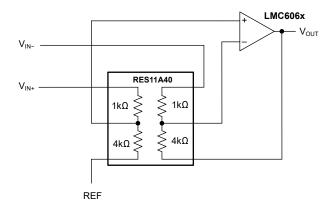






Table of Contents

1 Features 2 Applications	
3 Description	.1
4 Pin Configuration and Functions	
5 Specifications	. 5
5.1 Absolute Maximum Ratings	. 5
5.2 ESD Ratings	. 5
5.3 Recommended Operating Conditions	.5
5.4 Thermal Information: LMC6061	. 6
5.5 Thermal Information: LMC6062	. 6
5.6 Thermal Information: LMC6064	. 6
5.7 Electrical Characteristics	7
5.8 Typical Characteristics	11

6 Application and Implementation	. 15
6.1 Applications Information	
6.2 Typical Applications	
6.3 Layout	
7 Device and Documentation Support	20
7.1 Receiving Notification of Documentation Updates	.20
7.2 Support Resources	. 20
7.3 Trademarks	.20
7.4 Electrostatic Discharge Caution	
7.5 Glossary	
8 Revision History	
9 Mechanical, Packaging, and Orderable Information.	

4 Pin Configuration and Functions

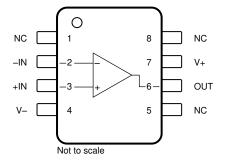


Figure 4-1. LMC6061: D Package, 8-Pin SOIC (Top View)

Table 4-1. Pin Functions: LMC6061

PIN		ТҮРЕ	DESCRIPTION	
NAME	NO.		DESCRIPTION	
-IN	2	Input	Inverting input	
+IN	3	Input	Noninverting input	
NC	1, 8, 5	_	No connection (can be left floating)	
OUT	6	Output	Output	
V–	4	Power	Negative (lowest) power supply	
V+	7	Power	Positive (highest) power supply	

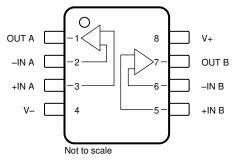
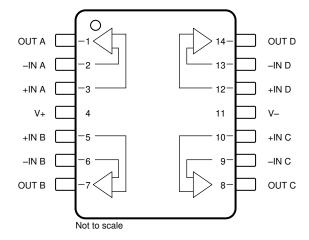


Figure 4-2. LMC6062: D Package, 8-Pin SOIC and P Package, 8-Pin PDIP (Top View)

PIN		TYPE	DECODIDE ON	
NAME	NO.	TYPE	DESCRIPTION	
–IN A	2	Input	Inverting input channel A	
–IN B	6	Input	Inverting input channel B	
+IN A	3	Input	Noninverting input channel A	
+IN B	5	Input	Noninverting input channel B	
OUT A	1	Output	Output channel A	
OUT B	7	Output	Output channel B	
V-	4	Power	Negative supply	
V+	8	Power	Positive supply	

Table 4-2. Pin Functions: LMC6062







PIN		TYPE	DESCRIPTION	
NAME	NO.	TYPE	DESCRIPTION	
-IN A	2	Input	Inverting input channel A	
–IN B	6	Input	Inverting input channel B	
–IN C	9	Input	Inverting input channel C	
–IN D	13	Input	Inverting input channel D	
+IN A	3	Input	Noninverting input channel A	
+IN B	5	Input	Noninverting input channel B	
+IN C	10	Input	Noninverting input channel C	
+IN D	12	Input	Noninverting input channel D	
OUT A	1	Output	Output channel A	
OUT B	7	Output	Output channel B	
OUT C	8	Output	Output channel C	
OUT D	14	Output	Output channel D	
V-	11	Power	Negative supply	
V+	4	Power	Positive supply	

Table 4-3. Pin Functions: LMC6064



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

			MIN	MAX	UNIT
	Differential input voltage			±Supply voltage	V
	Voltage at input/output pin		(V–) – 0.3	(V+) + 0.3	V
V_{S}	Supply voltage, $V_S = (V+) - (V-)$			16	V
	Output abort airquit aurrant	To V+		See ⁽³⁾	
I _{SC}	Output short circuit current	To V–		See ⁽⁴⁾	
	Current	At input pin		±10	
		At output pin		±30	mA
		At power supply pin		40	
	Power dissipation	i.		See ⁽⁵⁾	
	Lead temperature (soldering, 10s)			260	°C
ΤJ	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.

(3) Do not connect output to V+, when V+ is greater than 13V or reliability can be adversely affected.

(4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of ±30mA over long term can adversely affect reliability.

(5) The maximum power dissipation is a function of $T_{J(Max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(Max)} - T_A) / \theta_{JA}$

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM MAX	UNIT
	Supply voltage, V _S = (V+) – (V–)	Single supply	4.5	36	- V
Vs	Supply voltage, $v_S = (v_T) = (v_{-})$	Dual supply	±2.25	±18	
	Specified temperature		-40	125	°C
	Power dissipation			See ⁽¹⁾	

(1) To operate the device at elevated temperatures, derate the device based on thermal resistance θ_{JA} with $P_D = (T_J - T_A) / \theta_{JA}$.



5.4 Thermal Information: LMC6061

		LMC6061	
	THERMAL METRIC ⁽¹⁾	D (SOIC)	UNIT
		8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	193.0	°C/W
R _{0JC(top)}	Junction-to-case(top) thermal resistance	57.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	62.3	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	10.0	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	61.5	°C/W
R _{0JC(bot)}	Junction-to-case(bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.5 Thermal Information: LMC6062

THERMAL METRIC ⁽¹⁾		LM	LMC6062	
		D (SOIC)	P (PDIP)	UNIT
		8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	193.0	115.0	°C/W
R _{0JC(top)}	Junction-to-case(top) thermal resistance	52.0	59.2	°C/W
R _{θJB}	Junction-to-board thermal resistance	56.9	43.2	°C/W
Ψյт	Junction-to-top characterization parameter	6.8	25.1	°C/W
Ψјв	Junction-to-board characterization parameter	56.1	42.3	°C/W
R _{0JC(bot)}	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.6 Thermal Information: LMC6064

		LMC6064	
	THERMAL METRIC ⁽¹⁾	D (SOIC)	UNIT
		14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	126.0	°C/W
R _{0JC(top)}	Junction-to-case(top) thermal resistance	34.6	°C/W
R _{θJB}	Junction-to-board thermal resistance	34.3	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	4.7	°C/W
Ψјв	Junction-to-board characterization parameter	33.7	°C/W
R _{θJC(bot)}	Junction-to-case(bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



5.7 Electrical Characteristics

at $T_J = T_A = +25^{\circ}$ C, V+ = 5V, V- = 0V, V_{CM} = 1.5V, V_{OUT} = 2.5V, and R_L > 1M Ω connected to V+ / 2 (unless otherwise noted)

	PARAMETER	TEST CON	MIN	TYP	MAX	UNIT	
OFFSET	VOLTAGE						
		LMC606xAI			±100	±350	
V	Input offset voltage		$T_A = -40^{\circ}C$ to +85°C			±900	
V _{OS}	input onset voltage	LMC606xI			±100	±800	μv
			$T_A = -40^{\circ}C$ to +85°C			±1300	
dV _{OS} /dT	Input offset voltage drift	$T_A = -40^{\circ}C$ to +85°C			1		μV/°C
			LMC606xAI	75	85		
		Positive	LMC606xAl T _A = -40° C to $+85^{\circ}$ C	72			
		$5V \le V+ \le 15V$, $V_{OUT} = 2.5V$,	LMC606xI	66	85		fA pA fA pA fA pA fA/√Hz fA/√Hz %
PSRR	Power supply rejection ratio		$\frac{LMC606 \times I}{T_A = -40^{\circ}C \text{ to } +85^{\circ}C}$	63			٩D
FORR			LMC606xAI	84	100		uВ
		Negative	$\frac{LMC606xAI}{T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C}$	81			
		$-10V \le V + \le 0V$	LMC606xI	74	100		-
			$\frac{LMC606xI}{T_A = -40^{\circ}C \text{ to } +85^{\circ}C}$	71			
INPUT B	IAS CURRENT		1				
	Input biog ourrent				±10		fA
IB	Input bias current	$T_A = -40^{\circ}C$ to +85°C				±4	pА
	Input offect ourrent				±5		fA
l _{OS}	Input offset current	$T_A = -40^{\circ}C$ to +85°C				±4	pА
NOISE		•					
e _n	Input voltage noise density	f = 1kHz			83		nV/√Hz
i _n	Input current noise density	f = 1kHz			12.5		fA/√Hz
THD	Total Harmonic Distortion	f= 1kHz, G = $-5V/V$, R _L = $100k\Omega$, \	$V_{OUT} = 2V_{pp}, V_S = \pm 5V$		0.01		%
INPUT V	OLTAGE	•					
		To positive rail			(V+) – 1.9	(V+) – 2.3	
V _{CM}	Common-mode voltage	V+ = 15V and V+ = 5V, CMRR > 60dB	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			(V+) – 2.5	V
• Civi	Common mode vehage	To negative rail		- 0.1	- 0.4		•
		V+ = 15V and V+ = 5V, CMRR > 60dB	$T_A = -40^{\circ}C$ to +85°C	0			
			LMC606xAI	75	85		
	Common-mode rejection	V+ = 15V,	LMC606xAI, T _A = -40°C to +85°C	72			-ID
CMRR	ratio	$0V \le V_{CM} \le 12V$	LMC606xI	66	85		uБ
			LMC606xI, T _A = -40°C to +85°C	63			
INPUT IN	IPEDANCE	1					
R _{IN}	Input resistance				>10		ТΩ



5.7 Electrical Characteristics (continued)

at $T_J = T_A = +25^{\circ}C$, V+ = 5V, V- = 0V, $V_{CM} = 1.5V$, $V_{OUT} = 2.5V$, and $R_L > 1M\Omega$ connected to V+ / 2 (unless otherwise noted)

	PARAMETER	TEST CON	DITIONS	MIN	UNIT		
OPEN-L	.OOP GAIN						
			LMC606xAI	300	4000		
		Sourcing, V+ = 15V, V _{CM} = 7.5V,	LMC606xAI, T _A = -40°C to +85°C	200			
		$7.5V \le V_0 \le 11.5V, R_L = 100k\Omega$	LMC606xI	300	4000		
Aci			LMC606xI, T _A = -40°C to +85°C	200			
			LMC606xAI	180	3000		
		Sinking, V+ = 15V, V _{CM} = 7.5V,	LMC606xAI, T _A = -40°C to +85°C	100			
		$2.5V \le V_0 \le 7.5V$, R _L = 100k Ω	LMC606xI	90	3000		
	Open leep veltage gein		LMC606xI, T _A = -40°C to +85°C	60			– V/mV
A _{OL}	Open-loop voltage gain		LMC606xAI	300	3000		
		Sourcing, V+ = 15V, V _{CM} = 7.5V, 7.5V \leq V _O \leq 11.5V, R _L = 25k Ω	LMC606xAI, T _A = -40°C to +85°C	150			
			LMC606xI	200	3000		
			LMC606xI, T _A = -40°C to +85°C	80			
			LMC606xAI	100	2000		
		Sinking, V _S = 15V, V _{CM} = 7.5V,	LMC606xAI, T _A = -40°C to +85°C	50			
		$2.5V \le V_0 \le 7.5V$, $R_L = 25k\Omega$	LMC606xI	70	2000		
			LMC606xI, T _A = -40°C to +85°C	35			
FREQU	ENCY RESPONSE						
GBW	Gain bandwidth product				100		kHz
			LMC606xAI	20	35		
SR	Slew rate	V+ = 15V, 10V step, g = 1	LMC606xAI, -40°C to +85°C	10			V/ms
			LMC606xI	15	35		v/113
			LMC606xI, -40°C to +85°C	7			
	Crosstalk	Dual and quad channel, V+ = 15V, 12V _{pp}	R _L = 100kΩ, f = 100Hz, V _{OUT} =		155		dB



5.7 Electrical Characteristics (continued)

at $T_J = T_A = +25^{\circ}C$, V+ = 5V, V- = 0V, $V_{CM} = 1.5V$, $V_{OUT} = 2.5V$, and $R_L > 1M\Omega$ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST C	ONDITIONS	MIN	ТҮР	MAX	v
OUTPUT							
			LMC606xAI	4.990	4.995		
		Positive rail	LMC606xAI, T _A = -40°C to +85°C	4.980			
		V+ = 5V, R_L = 100k Ω	LMC606xI	4.950	4.995		
			LMC606xI, T _A = -40°C to +85°C	4.925			
			LMC606xAI		0.005	0.010	
		Negative rail	LMC606xAI, $T_A = -40^{\circ}C$ to +85°C			0.020	
	$V + = 5V, R_{L} = 100k\Omega$	LMC606xI		0.005	0.050		
			LMC606xI, T _A = -40°C to +85°C			0.075	
			LMC606xAI	4.975	4.990		
		Positive rail	LMC606xAI, T _A = -40°C to +85°C	4.965			20 50 75 75 20 35 50 50 V V 25 35 50
		V + = 5 V , R_L = 25 $k\Omega$	LMC606xI	4.950	4.990		
			LMC606xI, T _A = -40°C to +85°C	4.850			
			LMC606xAI		0.010	0.020	
		Negative rail	LMC606xAI, T _A = -40°C to +85°C			0.035	
		V + = 5 V , R_L = 25 $k\Omega$	LMC606xI		0.010	0.050	
Vo	Voltage output swing		LMC606xI, T _A = -40°C to +85°C			0.150	
۷O	voltage output swilig		LMC606xAI	14.975	14.990		v
		Positive rail	LMC606xAI, T _A = -40°C to +85°C	14.965			
		V+ = 15V, R _L = 100kΩ	LMC606xI	14.950	14.990		
			LMC606xI, T _A = -40°C to +85°C	14.925			V
			LMC606xAI		0.010	0.025	
		Negative rail	LMC606xAI, T _A = -40°C to +85°C			0.035	V
		$V + = 15V, R_{L} = 100k\Omega$	LMC606xI		0.010	0.050	
			LMC606xI, T _A = -40°C to +85°C			0.075	
			LMC606xAI	14.90	14.965		
		Positive rail	LMC606xAI, T _A = -40°C to +85°C	14.850			
		V+ = 15V, R_L = 25k Ω	LMC606xI	14.850	14.965		
			LMC606xI, T _A = -40°C to +85°C	14.800			
			LMC606xAI		0.025	0.050	
		Negative rail	LMC606xAI, T _A = -40°C to +85°C			0.150	
		V+ = 15V, R_L = 25k Ω	LMC606xI		0.025	0.100	
			LMC606xI, T _A = -40°C to +85°C			0.200	

5.7 Electrical Characteristics (continued)

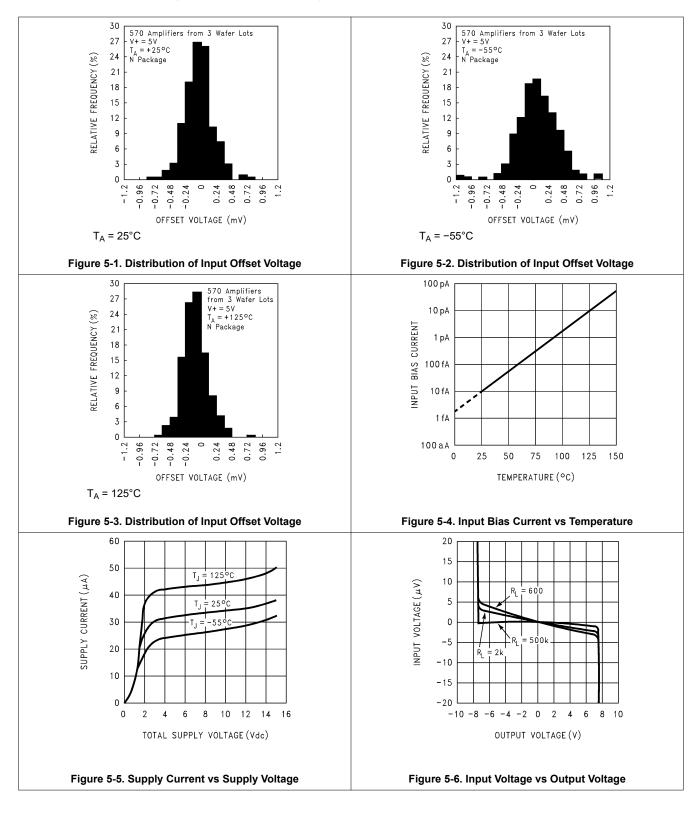
at $T_J = T_A = +25^{\circ}$ C, V+ = 5V, V- = 0V, V_{CM} = 1.5V, V_{OUT} = 2.5V, and R_L > 1M Ω connected to V+ / 2 (unless otherwise noted)

	PARAMETER	TEST CC	ONDITIONS	MIN	ТҮР	MAX	UNIT
			LMC606xAI	16	22		
		Sourcing	LMC606xAI, $T_A = -40^{\circ}C$ to +85°C	10			
		V _{OUT} = 0V	LMC606xI	13	22		
			LMC606xI, T _A = -40°C to +85°C	8			
			LMC606xAI	16	21		
		Sinking	LMC606xAl, $T_A = -40^{\circ}C$ to +85°C	8			32 32 32 40 19 23 23 23 23 30 38 40 40 43 3.5 7.5 3.5
		V _{OUT} = 5V	LMC606xI	16	21		
	Short-circuit current		LMC606xI, T _A = -40°C to +85°C	8			m۸
I _{SC}	Short-circuit current		LMC606xAI	15	25		IIIA
		Sourcing	LMC606xAI, T _A = -40°C to +85°C	10			
		V+ = 15V, V _{OUT} = 0V	LMC606xI	15	25		
			LMC606xI, T _A = -40°C to +85°C	10			
			LMC606xAI	20	26		
		Sinking	LMC606xAI, $T_A = -40^{\circ}C$ to +85°C	8			
		V+ = 15V, V _{OUT} = 13V ⁽¹⁾	LMC606xI	20	26	24 32 32 40 19 23 23 23 23 28 30 38 40 48 23.5 27.5 28.5	
			LMC606xI, T _A = -40°C to +85°C	8			
POWE	R SUPPLY						
		LMC6061AI,			20	24	
		V _{OUT} = 1.5V	$T_A = -40^{\circ}C$ to +85°C			32	
		LMC6061I,			20	32	
		V _{OUT} = 1.5V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
		LMC6062AI and LMC6064AI,			16	-	
		V _{OUT} = 1.5V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
		LMC6062I and LMC6064I, V _{OUT} = 1.5V	-		16	-	
IQ	Quiescent current per amplifier		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				μΑ
		LMC6061AI, V _{OUT} = 7.5V, V+ = 15V	T = 40°C to :05°C		24		32 32 40 19 23 23 23 23 30 38 40 48 23.5
			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		24		
		LMC6061I, V _{OUT} = 7.5V, V+ = 15V	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$		24	-	
					20		
		LMC6062AI and LMC6064AI, V _{OUT} = 7.5V, V+ = 15V	T _A = -40°C to +85°C				
		LMC6062I and LMC6064I,			20		
		$V_{OUT} = 7.5V, V + = 15V$	T _A = -40°C to +85°C			33	

(1) Do not connect output to V+, when V+ is greater than 13V or reliability can be adversely affected.

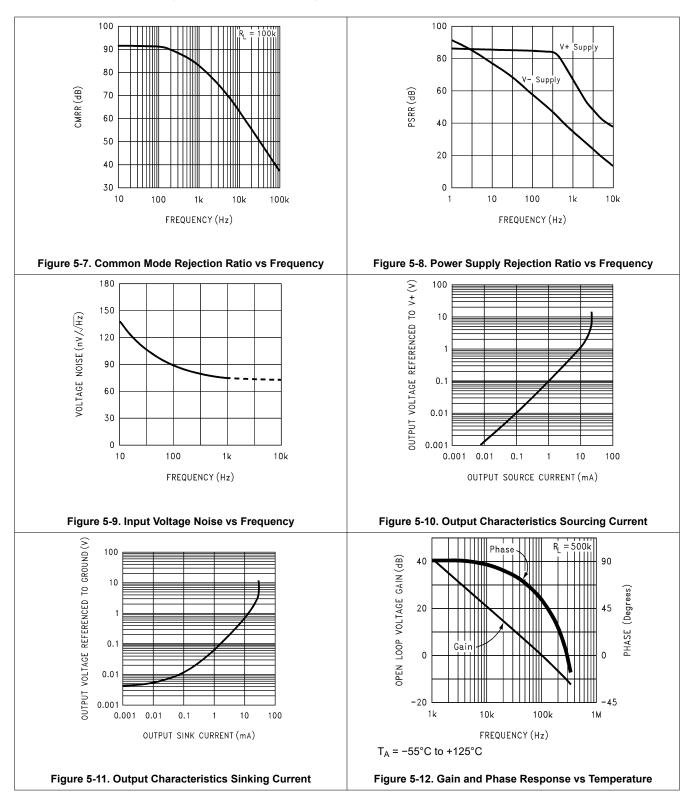


5.8 Typical Characteristics



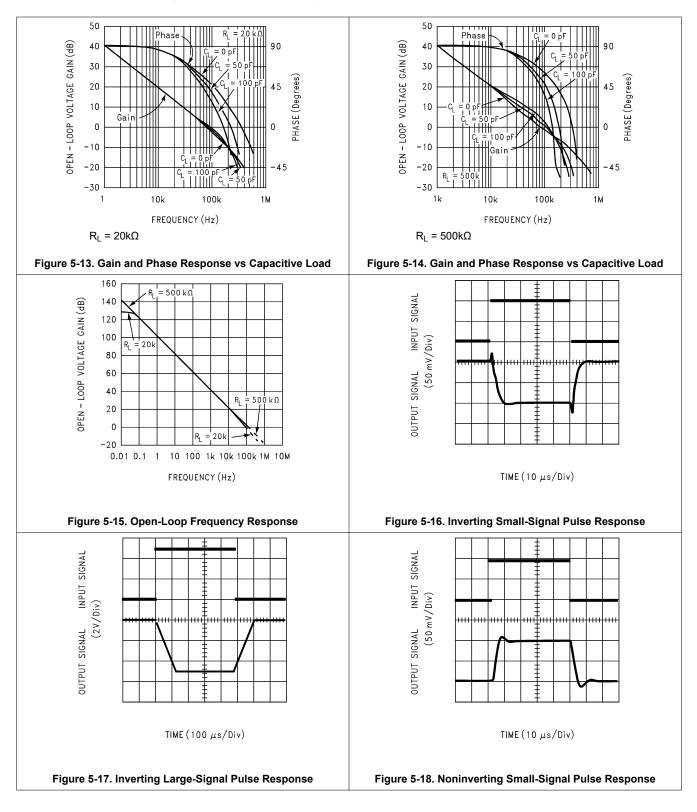


5.8 Typical Characteristics (continued)



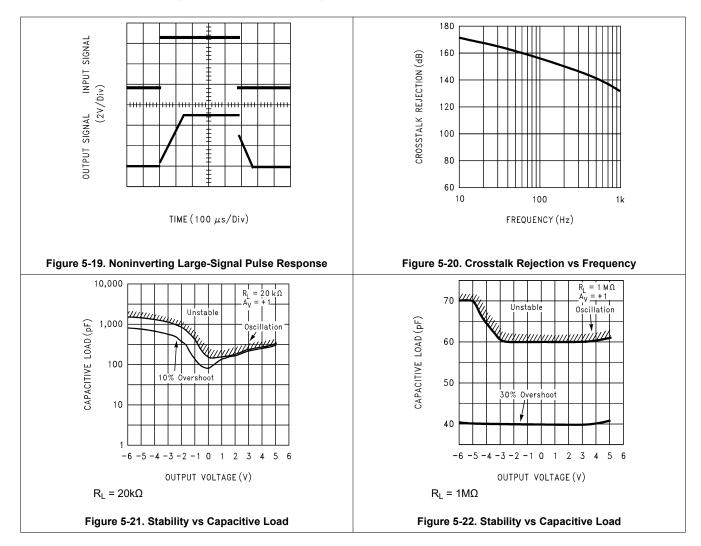


5.8 Typical Characteristics (continued)





5.8 Typical Characteristics (continued)





6 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

6.1 Applications Information

6.1.1 Amplifier Topology

The LMC606x incorporate a novel op amp design topology that enables rail-to-rail output swing even when driving a large load. Special compensation design techniques are incorporated to maintain stability over a wider range of operating conditions than traditional micropower op amps. These features make the LMC606x both easier to design with, and provide higher speed than products typically found in this ultra-low power class.

6.1.2 Compensating For Input Capacitance

Large values of feedback resistance are quite common for amplifiers with ultra-low input current, like the LMC606x. Although the LMC606x is highly stable over a wide range of operating conditions, take certain precautions to achieve the desired pulse response when a large feedback resistor is used. Large feedback resistors and even small values of input capacitance, due to transducers, photodiodes, and circuit board parasitics, reduce phase margins.

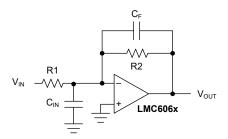
When high input impedances are demanded, guarding of the LMC606x is suggested. Guarding input lines can not only reduce leakage, but also lower stray input capacitance. See also Section 6.3.1.1.

The effect of input capacitance can be compensated for by adding a capacitor. Place a capacitor, C_F , around the feedback resistor (as in Figure 6-1) such that:

$$\frac{1}{2\pi R 1 C_{\rm IN}} \ge \frac{1}{2\pi R 2 C_{\rm F}} \tag{1}$$

where

 $R1C_{IN} \le R2C_{F}$



(2)

Figure 6-1. Canceling the Effect of Input Capacitance

The exact value of C_{IN} is often difficult to know, but C_F can be experimentally adjusted so that the desired pulse response is achieved. For a more detailed discussion on compensating for input capacitance, see the LMC660 and the LMC662.



6.1.3 Capacitive Load Tolerance

All rail-to-rail output swing operational amplifiers have voltage gain in the output stage. A compensation capacitor is normally included in this integrator stage. The frequency location of the dominate pole is affected by the resistive load on the amplifier. Capacitive load driving capability can be optimized by using an appropriate resistive load in parallel with the capacitive load (see *Section 5.8*).

Direct capacitive loading reduces the phase margin of many op amps. A pole in the feedback loop is created by the combination of the output impedance of the op amp and the capacitive load. This pole induces phase lag at the unity-gain crossover frequency of the amplifier resulting in either an oscillatory or underdamped pulse response. Figure 6-2 shows that with a few external components, op amps can easily indirectly drive capacitive loads.

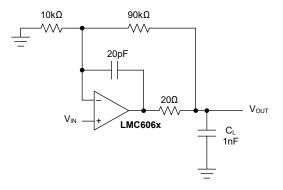


Figure 6-2. LMC606x Noninverting Gain of 10 Amplifier Compensated to Handle Capacitive Loads

In the circuit of Figure 6-2, R1 and C1 serve to counteract the loss of phase margin by feeding the high-frequency component of the output signal back to the inverting input of the amplifier, thereby preserving phase margin in the overall feedback loop.

Capacitive load driving capability is enhanced by using a pullup resistor to V+ (Figure 6-3). Typically, a pullup resistor conducting 10μ A or more can significantly improve capacitive load responses. The value of the pullup resistor must be determined based on the current sinking capability of the amplifier with respect to the desired output swing. The open-loop gain of the amplifier can also be affected by the pullup resistor (see Section 5.7).

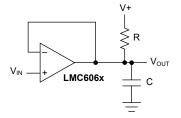


Figure 6-3. Compensating for Large Capacitive Loads With a Pullup Resistor

6.1.4 Latchup

CMOS devices tend to be susceptible to latchup due to internal parasitic silicon controlled rectifier (SCR) effects. The input and output (I/O) pins look similar to the gate of the SCR. There is a minimum current required to trigger the SCR gate lead. The LMC606x are designed to withstand 100mA surge current on the I/O pins. Use a resistive method to isolate any capacitance from supplying excess current to the I/O pins. In addition, like a SCR, there is a minimum holding current for any latchup mode. Limiting current to the supply pins also inhibits latchup susceptibility.



6.2 Typical Applications

6.2.1 Instrumentation Amplifier

The extremely high input impedance, and low power consumption, of the LMC606x make them an excellent choice for applications that require battery-powered instrumentation amplifiers. Examples of these types of applications are portable pH probes, analytic medical instruments, magnetic field detectors, gas detectors, and silicon-based pressure transducers.

Figure 6-4 shows an instrumentation amplifier that features high differential and common mode input resistance (> $10^{14}\Omega$), 0.01% gain accuracy at A_V = 100, excellent CMRR with 1k Ω imbalance in bridge source resistance. Input current is less than 100fA and offset drift is less than 2.5µV/°C. R2 provides a simple means of adjusting gain over a wide range without degrading CMRR. R7 is an initial trim used to maximize CMRR without using super precision matched resistors. For good CMRR over temperature, use low-drift resistors.

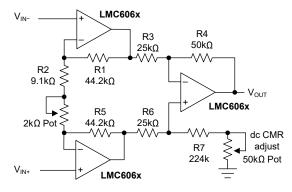


Figure 6-4. Instrumentation Amplifier

If R1 = R5, R3 = R6, and R4 = R7, then

$$\frac{V_{\text{OUT}}}{V_{\text{IN}}} = \frac{R4}{R3} \left(\frac{R2 + 2R1}{R2} \right)$$
(3)

and $A_V \cong 100$ for the circuit shown in Figure 6-4 (R2 = 9.1k Ω). Note that $V_{IN} = V_{IN+} - V_{IN-}$.

6.2.2 Low-Leakage Sample-and-Hold

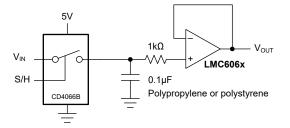


Figure 6-5. Low-Leakage Sample-and-Hold



6.2.3 1Hz Square-Wave Oscillator

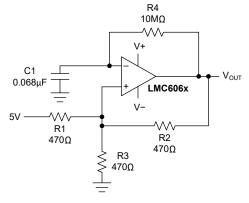


Figure 6-6. 1Hz Square-Wave Oscillator

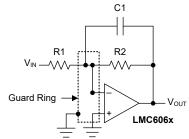
6.3 Layout

6.3.1 Layout Guidelines

6.3.1.1 Printed Circuit Board Layout For High Impedance Work

Generally, any circuit that must operate with less than 1000pA of leakage current requires special layout of the printed circuit board (PCB). To take advantage of the ultra-low bias current of the LMC606x, typically less than 10fA, having an excellent layout is essential. Fortunately, the techniques used to obtain low leakages are quite simple. First, do not ignore the surface leakage of the PCB, even though the leakage can sometimes appear acceptably low. Under conditions of high humidity, dust, or contamination, the surface leakage can be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LMC606x inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, and so on, connected to the op amp inputs, as in Figure 6-11. To have a significant effect, place guard rings on both the top and bottom of the PCB. Then connect this foil to a voltage that is at the same voltage as the amplifier inputs, because no leakage current can flow between two points at the same potential. For example, a PCB trace-to-pad resistance of $10^{12}\Omega$, which is normally considered a very large resistance, can leak 5pA if the trace is a 5V bus adjacent to the pad of the input. This leak can cause a 100 times degradation from the LMC606x actual performance. However, if a guard ring is held within 5mV of the inputs, then even a resistance of $10^{11}\Omega$ causes only 0.05pA of leakage current. See Figure 6-7 to Figure 6-9 for typical connections of guard rings for standard op amp configurations.



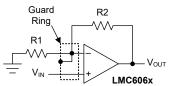
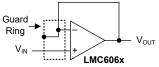


Figure 6-8. Typical Connections of Guard Rings: Noninverting Amplifier

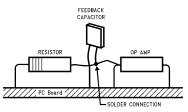








When laying out a PCB for the sake of just a few circuits is not practical, the following technique is even better than a guard ring. Do not insert the input pin of the amplifier into the PCB at all. Instead, bend the pin up in the air, and use only air as an insulator. Air is an excellent insulator. In this case, you forgo some of the advantages of PCB construction, but the advantages are sometimes well worth the effort of using point-to-point up-in-the-air wiring. Figure 6-10 shows an example of air wiring.



Note: Input pins are lifted out of the PCB and soldered directly to components. All other pins are connected to the PCB.

Figure 6-10. Air Wiring

6.3.2 Layout Example

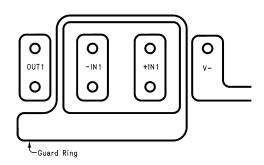


Figure 6-11. Example of Guard Ring in PCB Layout



7 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

7.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

7.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

7.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

7.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

8 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision D (March 2013) to Revision E (March 2025)	Page
•	Added LMC6061 and LMC6064 and related content to this data sheet	1
•	Deleted LMC6061 and LMC6064 PDIP content	1
•	Added application circuit	
•	Added Pin Configuration and Functions	
•	Updated pin names in Pin Configuration and Functions	
•	Added ESD Ratings	
•	Deleted notes 1 and 2 from Recommended Operating Conditions	
•	Added Thermal Information	6
•	Updated to combine ac and dc Electrical Characteristics	7
•	Updated parameter names and symbols	7
•	Deleted notes 1, 2, and 3 from dc Electrical Characteristics	7
•	Changed input current noise from 0.2fA/√Hz to 12.5fA/Hz	7
•	Moved note 4 conditions from dc Electrical Characteristics to open-loop voltage gain test conditions	7
•	Changed open-loop gain for $R_L = 100 k\Omega$ (sourcing) from 400V/mV to 300V/mV for LMC606xAI	7
•	Changed open-loop gain for $R_L = 100k\Omega$ (sourcing, $T_A = -40^{\circ}C$ to +85°C) from 300V/mV to 200V/mV	
	for LMC606xAI	7
•	Changed open-loop gain for RL = $25k\Omega$ (sourcing) from $400V/mV$ to $300V/mV$ for LMC606xAI	7
•	Deleted notes 1, 2, and 3 from ac Electrical Characteristics	7
•	Moved note 4 conditions from ac <i>Electrical Characteristics</i> to slew rate test conditions	7



•	Moved note 5 conditions from ac <i>Electrical Characteristics</i> to crosstalk test conditions
•	Change supply current parameter name to quiescent current per amplifier7
•	Updated Amplifier Topology15

С	hanges from Revision C (March 2013) to Revision D (March 2013)	Page
•	Changed layout of National Data Sheet to TI format	17

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMC6061AIM/NOPB	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	LMC60 61AIM	
LMC6061AIMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 61AIM	Samples
LMC6061IM/NOPB	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	LMC60 61IM	
LMC6061IMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 61IM	Samples
LMC6062AIM/NOPB	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	LMC60 62AIM	
LMC6062AIMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 62AIM	Samples
LMC6062I MDC	ACTIVE	DIESALE	Y	0	288	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 85		Samples
LMC6062IM/NOPB	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	LMC60 62IM	
LMC6062IMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 62IM	Samples
LMC6062IN/NOPB	ACTIVE	PDIP	Р	8	40	RoHS & Green	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LMC6062 IN	Samples
LMC6064AIM/NOPB	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	LMC6064 AIM	
LMC6064AIMX/NOPB	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC6064 AIM	Samples
LMC6064IM/NOPB	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	LMC6064IM	
LMC6064IMX/NOPB	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC6064IM	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE**: TI has discontinued the production of the device.



www.ti.com

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

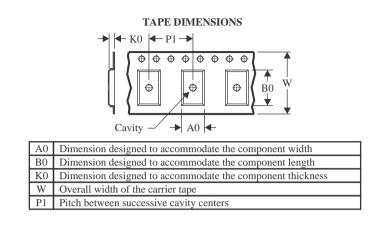


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMC6061AIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMC6061IMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMC6062AIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMC6062IMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMC6064AIMX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMC6064IMX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

11-Jan-2025



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)			
LMC6061AIMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0			
LMC6061IMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0			
LMC6062AIMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0			
LMC6062IMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0			
LMC6064AIMX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0			
LMC6064IMX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0			

TEXAS INSTRUMENTS

www.ti.com

11-Jan-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
LMC6062IN/NOPB	Р	PDIP	8	40	502	14	11938	4.32

D0014A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



D0014A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0014A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated